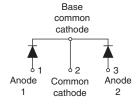


Schottky High Performance Rectifier Gen 3, D-61 Package, 2 x 40 A

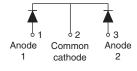
VS-82CNQ030APbF





VS-82CNQ030ASMPbF





Base

common

Anode

D-61-8-SM

VS-82CNQ030ASLPbF





D-61-8-SL

PRODUCT SUMMARY				
Package	D-61			
I _{F(AV)}	2 x 40 A			
V_{R}	30 V			
V _F at I _F	0.47			
I _{RM} max.	280 mA at 125 °C			
T _J max.	150 °C			
Diode variation	Common cathode			
E _{AS}	36 mJ			

FEATURES

- 150 °C T_J operation
- Dual center tap module
- Very low forward voltage drop
- High frequency operation
- High power discrete
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- New fully transfer-mould low profile, small footprint, high current package
- Through-hole versions are currently available for use in lead (Pb)-free applications ("PbF" suffix)
- · Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

Note

This datasheet provides information about parts that are RoHS-compliant and/or parts that are non-RoHS-compliant. For example, parts with lead (Pb) terminations are not RoHS-compliant. Please see the information/tables in this datasheet for details.

DESCRIPTION

The center tap Schottky rectifier module series has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	UNITS			
I _{F(AV)}	Rectangular waveform	80	Α		
V _{RRM}		30	V		
I _{FSM}	t _p = 5 μs sine	5100	Α		
V _F	40 A _{pk} , T _J = 125 °C (per leg)	0.37	V		
T_J	Range	-55 to +150	°C		

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-82CNQ030APbF	UNITS		
Maximum DC reverse voltage	V_{R}	30	V		
Maximum working peak reverse voltage	V_{RWM}	V _{RWM} 30			

VS-82CNQ030APbF Series

Vishay Semiconductors

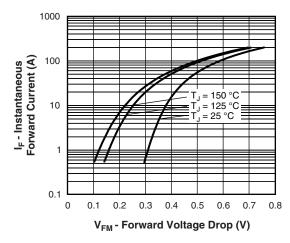
ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 119 °C, rectangular waveform		80	
Maximum peak one cycle non-repetitive surge current per leg	l=a	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with	5100	Α
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	880	
Non-repetitive avalanche energy per leg	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 8 \text{A}, L = 1.12 \text{mH}$		36	mJ
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		8	Α

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop per leg See fig. 1	V _{FM} ⁽¹⁾	40 A	T _J = 25 °C	0.47	V
		80 A		0.55	
		40 A	T _J = 125 °C	0.37	
		80 A		0.47	
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	V _R = Rated V _R	5	mA
See fig. 2		T _J = 125 °C		280	IIIA
Maximum junction capacitance per leg	C _T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		3700	pF
Typical series inductance per leg	L _S	Measured lead to lead 5 mm from package body		5.5	nΗ
Maximum voltage rate of change	dV/dt	Rated V _R 10 000		10 000	V/µs

Note

 $^{^{(1)}\,}$ Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range		T _J , T _{Stg}		-55 to +150	°C	
Maximum thermal resistance, per leg	per leg	0	DC operation (see fig. 4)	0.85		
junction to case	per package	R _{thJC}	DC operation	0.42	°C/W	
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased Device flatness < 5 mils	0.30		
Approximate weight				7.8	g	
Approximate weight				0.28	OZ.	
Mounting torque —	minimum			40 (35)	kgf · cm	
	maximum			58 (50)	(lbf · in)	
Marking device			Case style D-61	82CNQ	030A	
			Case style D-61-8-SM	82CNQ03	30ASM	
			Case style D-61-8-SL	82CNQ03	30ASL	





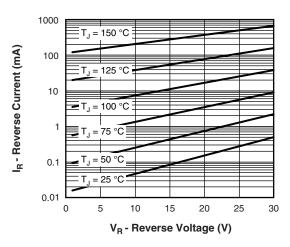


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

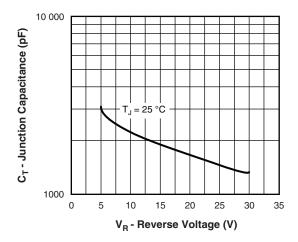


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

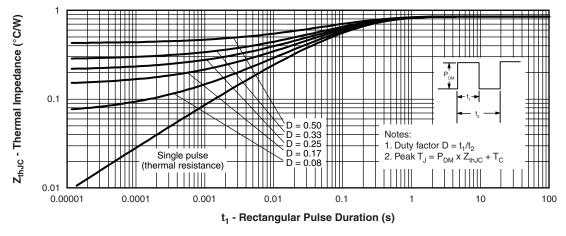


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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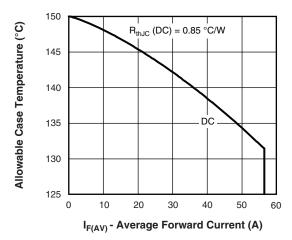


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

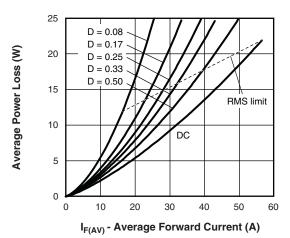


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

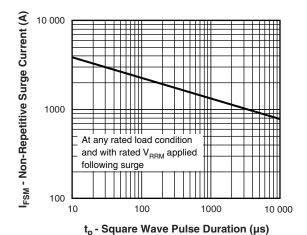


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

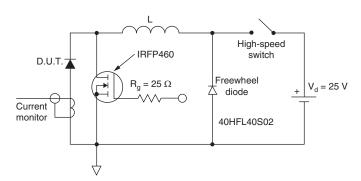


Fig. 8 - Unclamped Inductive Test Circuit

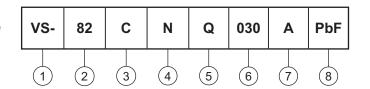
Note

 $^{(1)}$ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{th,JC}; Pd = Forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (80 A)

Circuit configuration:

C = common cathode

4 - Package:

N = D-61

5 - Schottky "Q" series

6 - Voltage ratings (030 = 30 V)

7 - Package style:

• A = D-61-8

• ASM = D-61-8-SM

• ASL = D-61-8-SL

8 - • None = standard production

• PbF = lead (Pb)-free

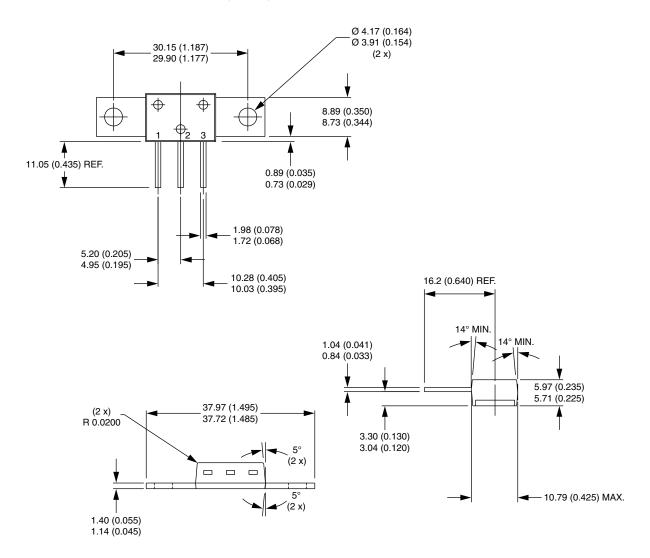
Standard pack quantity: A = 10 pieces; ASM/ASL = 20 pieces

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95354			
Part marking information	www.vishay.com/doc?95356			



D-61-8, D-61-8-SM, D-61-8-SL

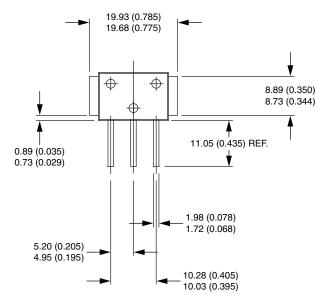
DIMENSIONS - D-61-8 in millimeters (inches)

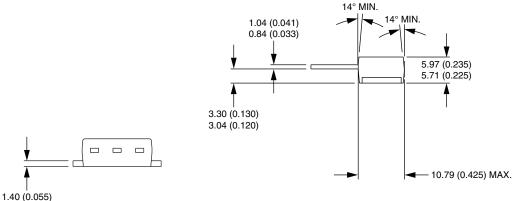




DIMENSIONS - D-61-8-SM in millimeters (inches)

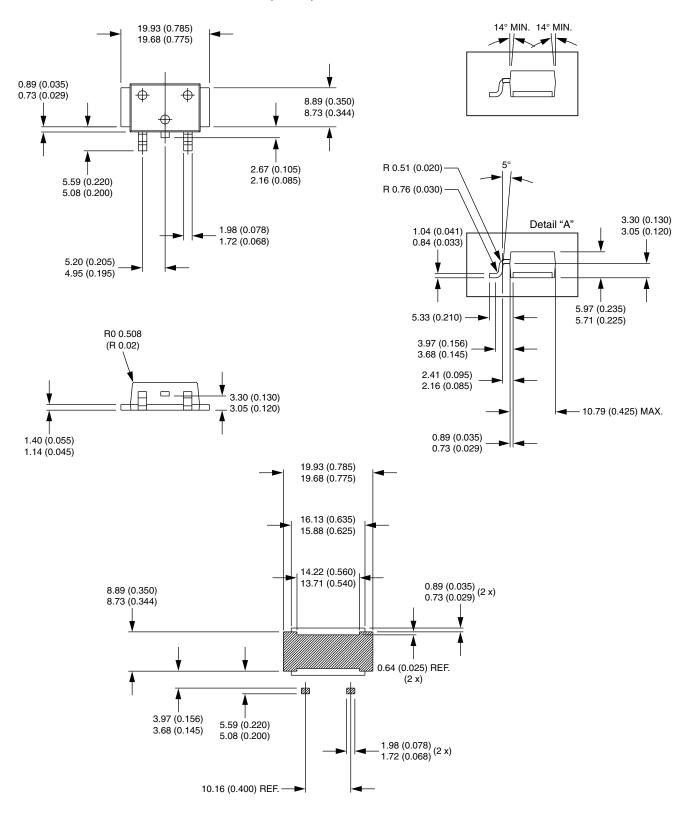
1.14 (0.045)







DIMENSIONS - D-61-8-SL in millimeters (inches)





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Revision: 02-Oct-12 Document Number: 91000